



A Product Line of **Diodes Incorporated** 

# SEMICONDUCTOR **G20E120CTSW**

**LITE-ON** 

TRENCH SCHOTTKY RECTIFIER	REVERSE VOLTAGE – 120 Volts FORWARD CURRENT – 20 Amperes			
<ul> <li>FEATURES <ul> <li>High efficiency</li> <li>Reduced high temperature reverse leakage</li> <li>Reduced ultra-low forward voltage drop</li> <li>Qualification is according to AEC-Q101 Rev_C</li> <li>Lead-Free Finish; RoHS Compliant (Notes 1 &amp; 2)</li> <li>Halogen and Antimony Free. "Green" Device (Note 3)</li> </ul> </li> <li>APPLICATION <ul> <li>DC to DC converters</li> <li>AC to DC adaptors</li> </ul> </li> <li>MECHANICAL DATA <ul> <li>Package: JEDEC TO-220ABFP</li> <li>Package Material: "Green" molding compound, UL flammability classification 94V-0, "Halogen-free".</li> <li>Lead free finish, RoHS compliant</li> </ul> </li> </ul>		S)AB IT DIM A B C D E F G G H I J K L N	O-220(S)A MIN 14.95 10.00 2.76 8.50 2.10 13.00 1.15 2.40 0.50 0.45 3.00 4.46 2.48 2.50 nsion in m	B MAX 15.95 10.40 3.36 8.80 2.50 13.70 1.37 2.70 0.80 0.70 3.30 4.87 2.80 2.80
Weight: 1.558 grams (Approximate)     Marking code: G20E120CTSW	PIN 3 • PIN 2			
MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS Ratings at 25°C ambient temperature unless otherwise specified.				

#### **ABSOLUTE RATINGS**

PARAMETER		SYMBOL	VALUE	UNIT
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	120	V
Maximum DC blocking voltage		V <sub>DC</sub>	120	V
Maximum Average rectified output current @Tc=85°C		I <sub>(AV)</sub>	20	А
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load.		I <sub>FSM</sub>	250	А
Non repetitive peak reverse current tp=2us		I <sub>RSM</sub>	3	А
Operating junction and Storage Temperature ran	ge	$T_{J,} T_{STG}$	-55 ~ +150	°C

### STATIC ELECTRICAL CHARACTERISTICS

PARAMETER	TEST C	TEST CONDITIONS		ТҮР	MAX	UNIT
Forward voltage (Note 4)	I <sub>F</sub> =10A	T <sub>J</sub> =25°C T <sub>J</sub> =125°C	V <sub>F</sub>	 0.66	0.83 0.76	V
Leakage current	V <sub>R</sub> =120V	T <sub>J</sub> =25°C T <sub>J</sub> =125°C	I <sub>R</sub>	 5.64	30 17	uA mA
Typical junction capacitance (N	ote 5)		CJ	37	5	pF

### THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	ТҮР	UNIT
Typical thermal resistance (Note 6.7)	RthJ <sub>c</sub>	4	°C/W
Typical thermal resistance (Note 0,7)	RthJ∟	6	C/ VV

Note:

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

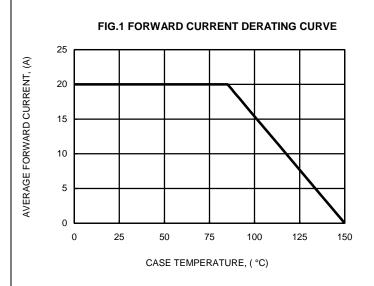
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. 300us pulse width, 2% duty cycle.
5. Measured at 1.0MHz and applied voltage of 4.0VDC.
6. Thermal resistance test performed in accordance with JESD-51.

7. The unit mounted on Aluminum plate heatsink (100.88mm x 75.34mm x 26.78mm).

RATING AND CHARACTERISTIC CURVES G20E120CTSW

### LITE-ON SEMICONDUCTOR



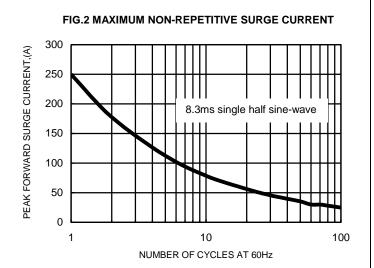
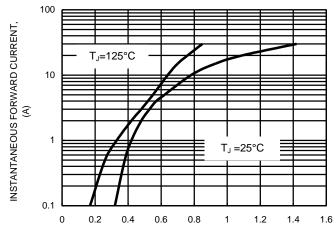


FIG.3 TYPICAL FORWARD CHARACTERISTICS



INSTANTANEOUS FORWARD VOLTAGE, (V)

60

RATED PEAK REVERSE VOLTAGE, (V)

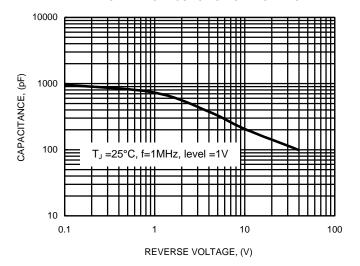
80

100

120

FIG.5 TYPICAL REVERSE CHARACTERISTICS

FIG.4 TYPICAL JUNCTION CAPACITANCE



INSTANTANEOUS REVERSE CURRENT,

(M)

10

1

0.1 L 0 T<sub>J</sub>=25°C

40

20

140

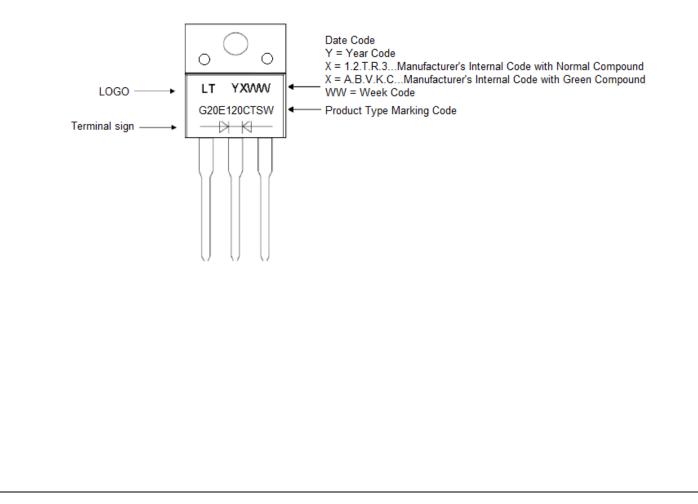


## LITE-ON SEMICONDUCTOR

# **Ordering Information:**

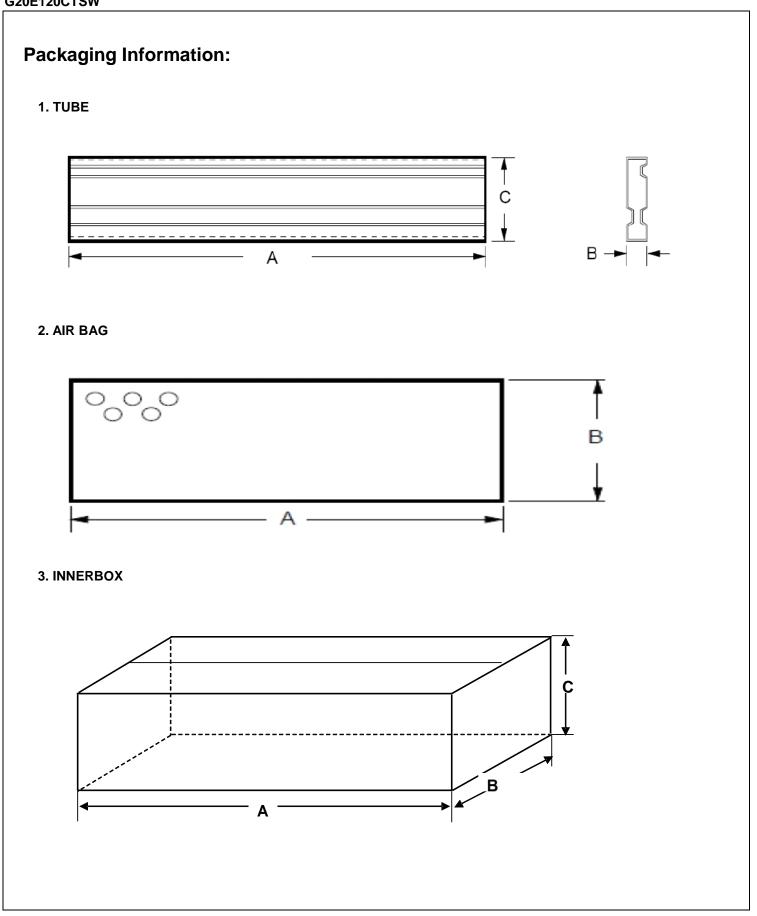
Dorf Number	Daakaga	Packing		
Part Number	Package	Qty.	Carrier	
G20E120CTSW	ITO-220(S)AB	50pcs	Tube	

## Marking Information:





## LITE-ON SEMICONDUCTOR

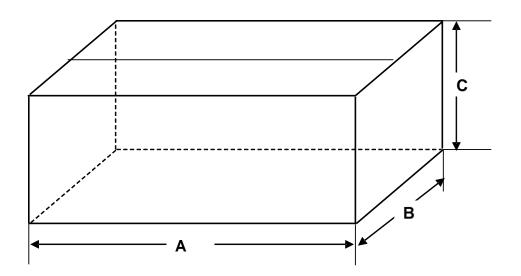






# Packaging Information (continued):

### 4. CARTON



### Unit: mm

P/N	DIMENSION "A"	DIMENSION "B"	DIMENSION "C"	Q'ty/per	REMARK
TUBE	536	5.6	31.8	50	1
AIR BAG	800	550	1	1	1
INNERBOX	555	165	105	2000	40TUBE
CARTON	575	179	225	4K	2 INNER BOX





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